## **UF1A THRU UF1M**



# SURFACE MOUNT ULTRAFAST RECOVERY RECTIFIER

REVERSE VOLTAGE: 50 to 1000 VOLTS http://www.njzrg.com
FORWARD CURRENT: 1.0 AMPERE

### **FEATURES**

· For surface mounted applications

· Low profile package

· Built-in strain relief

· Easy pick and place

· Ultrafast recovery times for high efficiency

· Plastic package has Underwriters Laboratory

Flammability Classification 94V-O

· High temperature soldering : 260°C /10 seconds at terminals

### **MECHANICAL DATA**

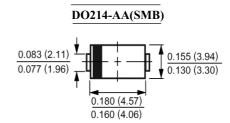
Case: Molded plastic, DO-214AA(SMB)

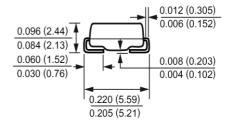
Terminals: Solder plated, solderable per MIL-STD-750,

method 2026 guaranteed

Polarity: Color band denotes cathode end Packaging: 12mm tape per EIA STD RS-481

Weight: 0.003 ounce, 0.093 gram





**Dimensions in inches and (millimeters)** 

### Maximum Ratings and Electrical Characteristics

Ratings at 25 ambient temperature unless otherwise specified.

Single phase, half wave,  $60H_Z$ , resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	UF1A	UF1B	UF1D	UF1G	UF1J	UF1K	UF1M	Units
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at $T_L$ =100	I <sub>(AV)</sub>				1.0				Amp
Peak Forward Surge Current,									
8.3ms single half-sine-wave	I <sub>FSM</sub> 30							Amp	
superimposed on rated load (JEDEC method)									
Maximum Forward Voltage at 1.0A	$V_{\rm F}$		1.0		1.3		1.7		Volts
Maximum Reverse Current at $T_A$ =25 at Rated DC Blocking Voltage $T_A$ =100	$I_R$	5.0 100							μАтр
Typical Junction Capacitance (Note 1)	$C_{J}$	17							pF
Typical Thermal Resistance (Note 2)	$R_{\theta JL}$	30							/W
Maximum Reverse Recovery Time (Note 3)	$T_{RR}$	50 75						nS	
Operating Junction Temperature Range	$T_{\mathbf{J}}$	-55 to +150							
Storage Temperature Range	Tstg	-55 to +150							

#### **NOTES:**

- 1- Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
- 2- Thermal resistance from junction to lead mounted on P.C.B. with 0.3 x 0.3" (8.0 x 8.0mm) copper pad areas
- 3- Reverse Recovery Test Conditions :  $I_F$ =.5A ,  $I_R$ =1A ,  $I_{RR}$ =.25A.



### RATINGS AND CHARACTERISTIC CURVES

http://www.njzrg.com

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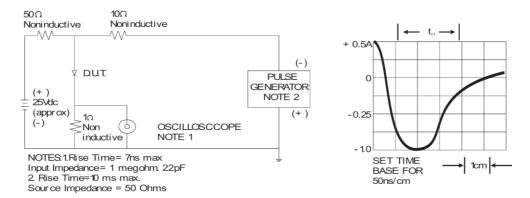


Fig. 1-REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

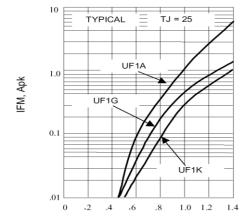


Fig. 2-FORWARD CHARACTERISTICS

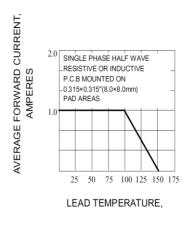


Fig. 3-FORWARD CURRENT DERATING CURVE

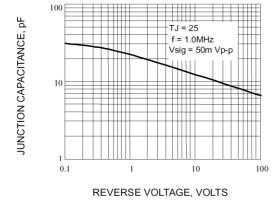


Fig. 4-TYPICAL JUNCTION CAPACITANCE

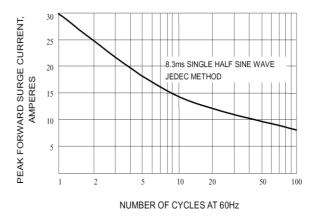


Fig. 5-PEAK FORWARD SURGE CURRENT